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High Performance Schottky Rectifier, 10 A

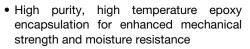


21	TO.	-220	AC

PRIMARY CHARACTERISTICS								
I _{F(AV)}	10 A							
V _R	35 V, 45 V							
V _F at I _F	0.57 V							
I _{RM} max.	15 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	8 mJ							
Package	2L TO-220AC							
Circuit configuration	Single							

FEATURES

- 150 °C T_J operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	10	^					
I _{FRM}	T _C = 135 °C	20	Α					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	1060	А					
V _F	10 A _{pk} , T _J = 125 °C	0.57	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBR1035-M3	VS-MBR1045-M3	UNITS				
Maximum DC reverse voltage	V_R	35	45	V				
Maximum working peak reverse voltage V _{RWM}		ან	40	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CO	ONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T _C = 135 °C, rated V _R	T _C = 135 °C, rated V _R					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20	Rated V _R , square wave, 20 kHz, T _C = 135 °C					
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V _{RRM} applied					
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 A, L = 4$	8	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to Frequency limited by T _J ma	2	Α				

VS-MBR1035-M3, VS-MBR1045-M3

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		20 A	T _J = 25 °C	0.84				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T. ₁ = 125 °C	0.57	V			
		20 A	1J = 125 C	0.72	1			
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA			
waximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	15				
Threshold voltage	V _{F(TO)}	T - T movimum		0.354	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		17.6	mΩ			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	600	pF				
Typical series inductance	L _S	Measured from top of term	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

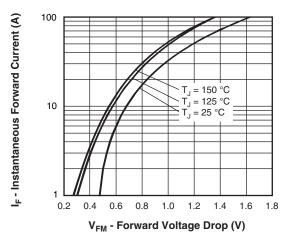
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ	TJ		°C				
Maximum storage temperature range	T _{Stg}		-65 to +175	C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.0	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque minimum			6 (5)	kgf · cm				
Mounting torque maximum			12 (10)	(lbf · in)				
Marking daving		Coop of the SL TO 200AC	MBR1035					
Marking device		Case style 2L TO-220AC	MBR	MBR1045				

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T_J = 150 °C I_R - Reverse Current (mA) 10 T_{.1} = 125 °C 1 T₁ = 100 °C 0.1 T_J = 75 °C $T_J = 50 \, ^{\circ}C$ 0.01 T_{.1} = 25 °C 0.001 0.0001 5 15 20 25 30 35 40 0 10 45 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

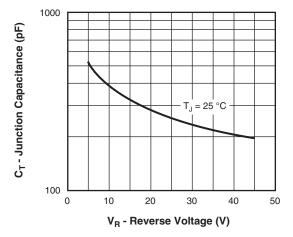


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

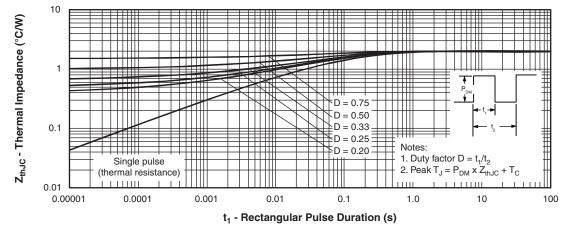


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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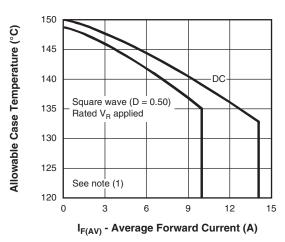


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

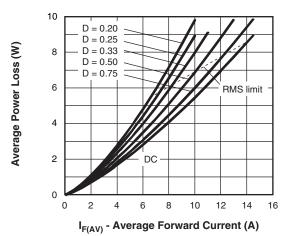


Fig. 6 - Forward Power Loss Characteristics

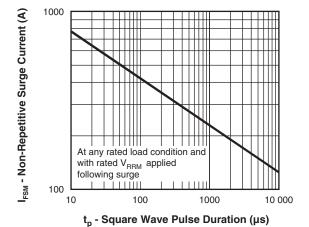


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

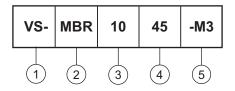
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = & \text{forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = & \text{inverse power loss} = V_{\text{R1}} \times I_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } V_{\text{R1}} = \text{rated } V_{\text{R}} \\ \end{array}$

VS-MBR1035-M3, VS-MBR1045-M3

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ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product

Schottky MBR series

- Currrent rating (10 = 10 A)

- Voltage ratings 35 = 35 V 45 = 45 V

5 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR1035-M3	50	1000	Antistatic plastic tube						
VS-MBR1045-M3	50	1000	Antistatic plastic tube						

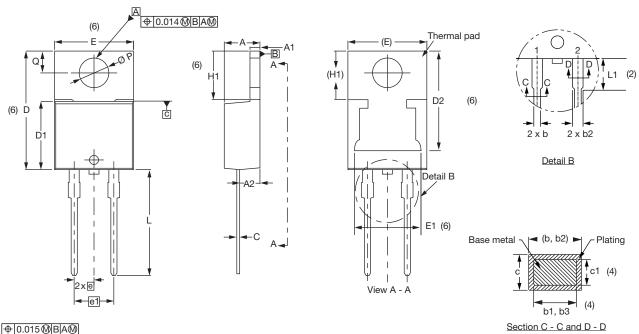
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96156</u>						
Part marking information	www.vishay.com/doc?95391					
SPICE model	www.vishay.com/doc?95293					

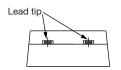


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2L TO-220AC

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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